



2SD1207S-AE Information



For Reference Only

Part Number 2SD1207S-AE
Manufacturer ON Semiconductor

Category Discrete Semiconductor Products
Transistors - Bipolar (BJT) - Single

Description TRANS NPN 50V 2A 3MP

Package TO-226-3, TO-92-3 Long Body (Formed Leads)

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









2SD1207S-AE Specifications

Manufacturer Part Number	2SD1207S-AE	
Manufacturer	ON Semiconductor	
Category	Discrete Semiconductor Products	
	Transistors - Bipolar (BJT) - Single	
Package	TO-226-3, TO-92-3 Long Body (Formed Leads)	
Series	-	
Transistor Type	NPN	
Current - Collector (Ic) (Max)	2A	
Voltage - Collector Emitter Breakdown (Max)	50V	
Vce Saturation (Max) @ Ib, Ic	400mV @ 50mA, 1A	
Current - Collector Cutoff (Max)	100nA (ICBO)	
DC Current Gain (hFE) (Min) @ Ic, Vce	100 @ 100mA, 2V	
Power - Max	1W	
Frequency - Transition	150MHz	
Operating Temperature	150°C (TJ)	
Mounting Type	Through Hole	
Package / Case	TO-226-3, TO-92-3 Long Body (Formed Leads)	
Supplier Device Package	3-MP	
	Report	errors?

2SD1207S-AE Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

2SD1207S-AE Payment Methods



















2SD1207S-AE Shipping Methods













If you have any question about 2SD1207S-AE, please do not hesitate to contact us!

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